

*“Evidence of magnetostrictive effects on STT-MRAM performance by atomistic and spin modeling”*. Sankaran K, Swerts J, Carpenter R, Couet S, Garelo K, Evans RFL, Rao S, Kim W, Kundu S, Crotti D, Kar GS, Pourtois G, 2018 Ieee International Electron Devices Meeting (iedm) (2018)